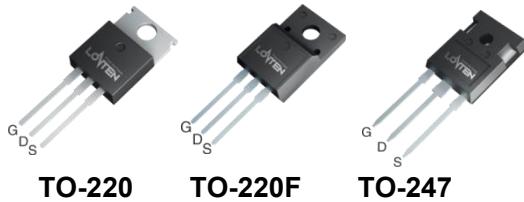
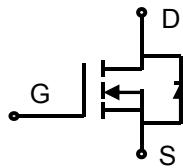


Lonten N-channel 650V, 20A Power MOSFET

| Description | Product Summary |
|---|--|
| <p>The Power MOSFET is fabricated using the advanced planer VDMOS technology. The resulting device has low conduction resistance, superior switching performance and high avalanche energy.</p> | <p>V_{DSS} 650V I_D 20A $R_{DS(on),max}$ 0.5Ω $Q_{g,typ}$ 58.3 nC</p> |
| | |
| Features | |
| <ul style="list-style-type: none"> ◆ Low $R_{DS(on)}$ ◆ Low gate charge (typ. $Q_g = 58.3$ nC) ◆ 100% UIS tested ◆ RoHS compliant |  <p>TO-220 TO-220F TO-247</p> |
| | |
| Applications | |
| <ul style="list-style-type: none"> ◆ Power factor correction. ◆ Switched mode power supplies. ◆ LED driver. |  <p>N-Channel MOSFET</p>  |

Absolute Maximum Ratings

| Parameter | Symbol | Value | Unit |
|--|----------------|-------------|---------------------------|
| Drain-Source Voltage | V_{DSS} | 650 | V |
| Continuous drain current ($T_c = 25^\circ\text{C}$) ($T_c = 100^\circ\text{C}$) | I_D | 20 | A |
| | | 12.5 | A |
| Pulsed drain current ¹⁾ | I_{DM} | 80 | A |
| Gate-Source voltage | V_{GSS} | ± 30 | V |
| Avalanche energy, single pulse ²⁾ | E_{AS} | 720 | mJ |
| Peak diode recovery dv/dt ³⁾ | dv/dt | 5 | V/ns |
| Power Dissipation TO-220F ($T_c = 25^\circ\text{C}$) Derate above 25°C | P_D | 45 | W |
| | | 0.36 | $\text{W}/^\circ\text{C}$ |
| Power Dissipation TO-247/TO-220 ($T_c = 25^\circ\text{C}$) Derate above 25°C | | 250 | W |
| | | 2 | $\text{W}/^\circ\text{C}$ |
| Operating junction and storage temperature range | T_J, T_{STG} | -55 to +150 | $^\circ\text{C}$ |
| Continuous diode forward current | I_S | 20 | A |
| Diode pulse current | $I_{S,pulse}$ | 80 | A |

Thermal Characteristics

| Parameter | Symbol | Value | Unit | |
|---|-----------------|---------|---------------|---------------------------|
| | | TO-220F | TO-247/TO-220 | |
| Thermal resistance, Junction-to-case | $R_{\theta JC}$ | 2.78 | 0.5 | $^\circ\text{C}/\text{W}$ |
| Thermal resistance, Junction-to-ambient | $R_{\theta JA}$ | 62.5 | 40 | $^\circ\text{C}/\text{W}$ |

Package Marking and Ordering Information

| Device | Device Package | Marking | Units/Tube | Units/Reel |
|----------|----------------|----------|------------|------------|
| LNB20N65 | TO-247 | LNB20N65 | 30 | |
| LND20N65 | TO-220F | LND20N65 | 50 | |
| LNC20N65 | TO-220 | LNC20N65 | 50 | |

Electrical Characteristics

T_c = 25°C unless otherwise noted

| Parameter | Symbol | Test Condition | Min. | Typ. | Max. | Unit |
|--------------------------------------|----------------------|--|------|-------|----------|------|
| Static characteristics | | | | | | |
| Drain-source breakdown voltage | BV _{DSS} | V _{GS} =0 V, I _D =0.25 mA | 650 | - | - | V |
| Gate threshold voltage | V _{GS(th)} | V _{DS} =V _{GS} , I _D =0.25 mA | 2 | - | 4 | V |
| Drain cut-off current | I _{DSS} | V _{DS} =650 V, V _{GS} =0 V, T _j = 25°C T _j = 125°C | - | - | 1 100 | μA |
| Gate leakage current, Forward | I _{GSSF} | V _{GS} =30 V, V _{DS} =0 V | - | - | 100 | nA |
| Gate leakage current, Reverse | I _{GSSR} | V _{GS} =-30 V, V _{DS} =0 V | - | - | -100 | nA |
| Drain-source on-state resistance | R _{DSS(on)} | V _{GS} =10 V, I _D =10A | - | 0.42 | 0.5 | Ω |
| Dynamic characteristics | | | | | | |
| Input capacitance | C _{iss} | V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz | - | 2962 | - | pF |
| Output capacitance | C _{oss} | | - | 266 | - | |
| Reverse transfer capacitance | C _{rss} | | - | 18 | - | |
| Turn-on delay time | t _{d(on)} | V _{DD} = 325 V, I _D = 20A R _G = 10 Ω, V _{GS} =15 V | - | 18.8 | - | ns |
| Rise time | t _r | | - | 43.4 | - | |
| Turn-off delay time | t _{d(off)} | | - | 98.2 | - | |
| Fall time | t _f | | - | 16.9 | - | |
| Gate charge characteristics | | | | | | |
| Gate to source charge | Q _{gs} | V _{DD} =520 V, I _D =20 A, V _{GS} =0 to 10 V | - | 16.7 | - | nC |
| Gate to drain charge | Q _{gd} | | - | 19.3 | - | |
| Gate charge total | Q _g | | - | 58.3 | - | |
| Gate plateau voltage | V _{plateau} | | - | 5 | - | V |
| Reverse diode characteristics | | | | | | |
| Diode forward voltage | V _{SD} | V _{GS} =0 V, I _F =20A | - | - | 1.5 | V |
| Reverse recovery time | t _{rr} | V _R =325 V, I _F =20A dI _F /dt=100 A/μs | - | 492.8 | - | ns |
| Reverse recovery charge | Q _{rr} | | - | 7.46 | - | μC |
| Peak reverse recovery current | I _{rrm} | | - | 30.3 | - | A |

Notes:

1. Pulse width limited by maximum junction temperature.
2. L=10mH, I_{AS} = 12A, Starting T_j= 25°C.
3. I_{SD} = 20A, di/dt≤100A/us, V_{DD}≤BV_{DS}, Starting T_j= 25°C.

Electrical Characteristics Diagrams

Figure 1. Typical Output Characteristics

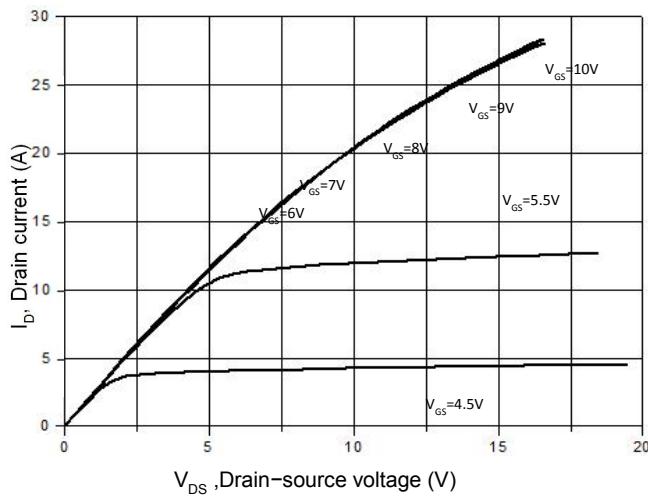


Figure 2. Transfer Characteristics

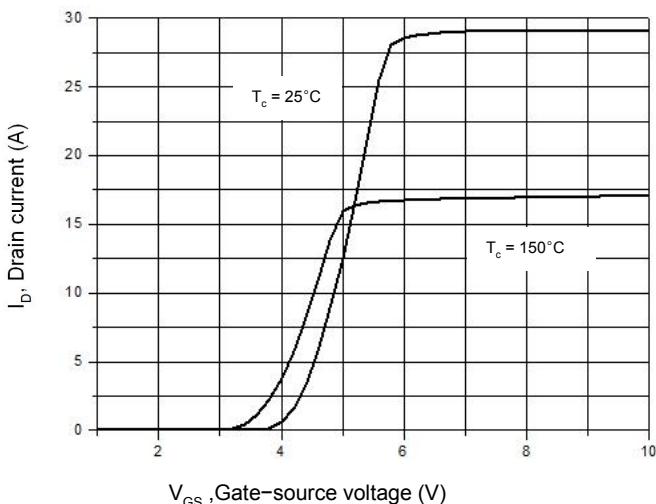


Figure 3. On-Resistance Variation vs. Drain Current

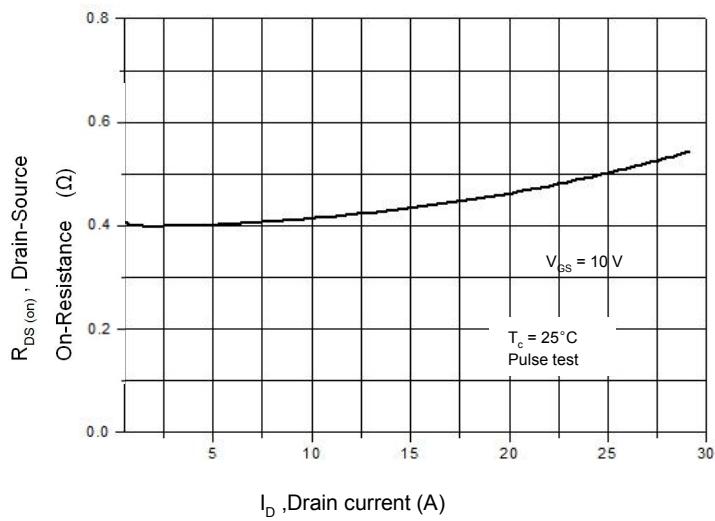


Figure 4. Threshold Voltage vs. Temperature

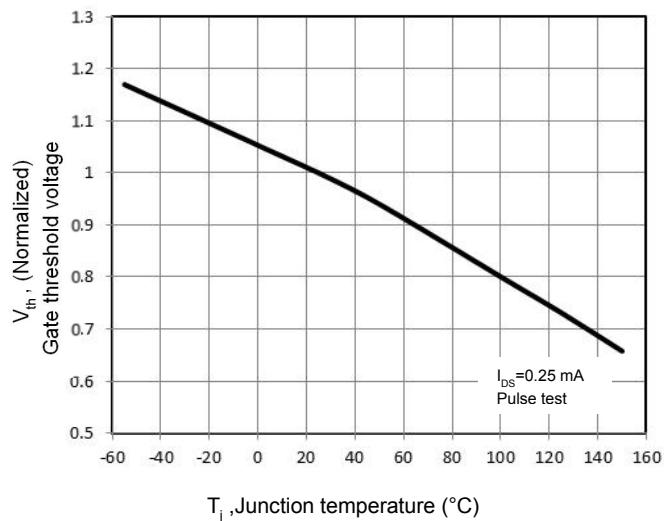


Figure 5. Breakdown Voltage vs. Temperature

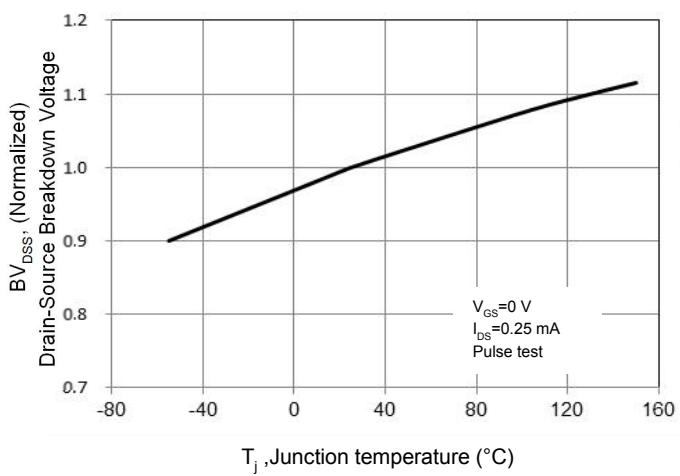


Figure 6. On-Resistance vs. Temperature

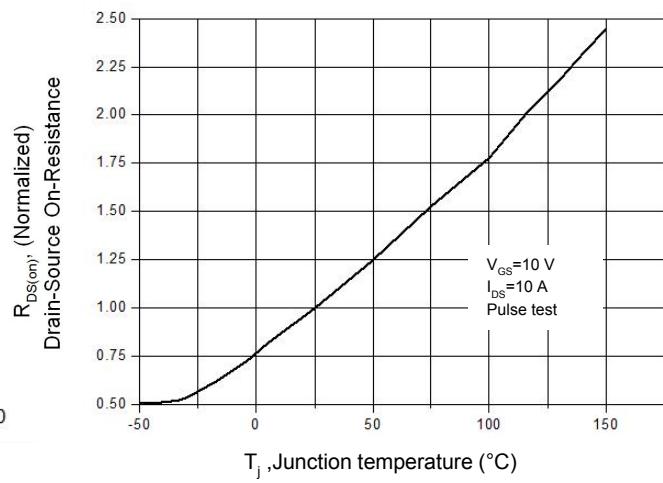


Figure 7. Capacitance Characteristics

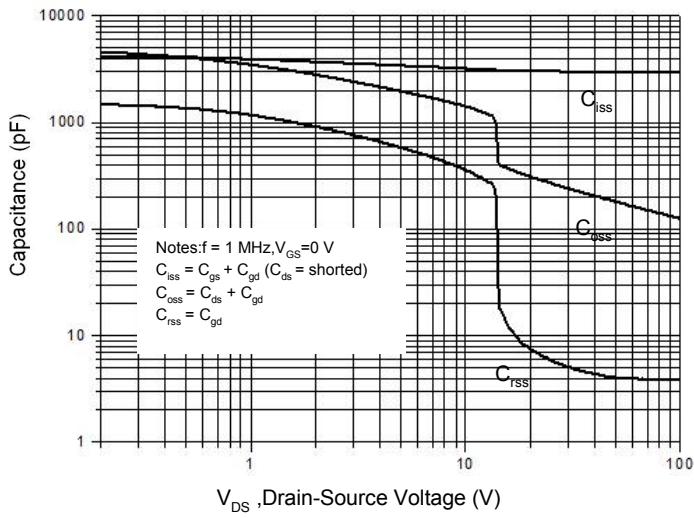


Figure 9. Maximum Safe Operating Area

TO-220F

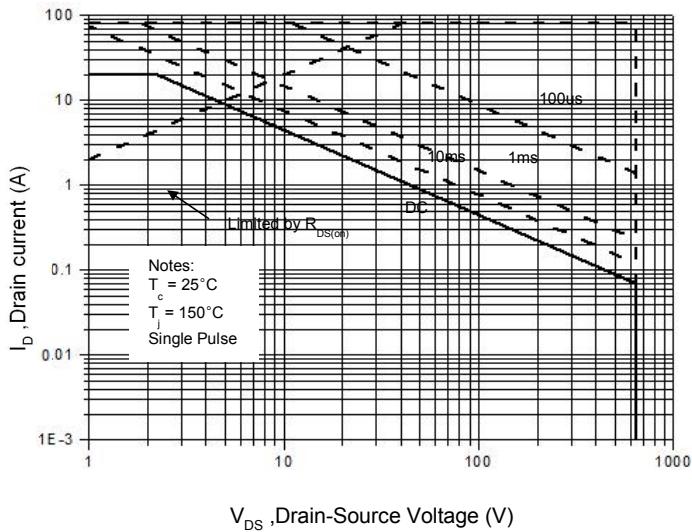


Figure 11. Power Dissipation vs. Temperature

TO-220F

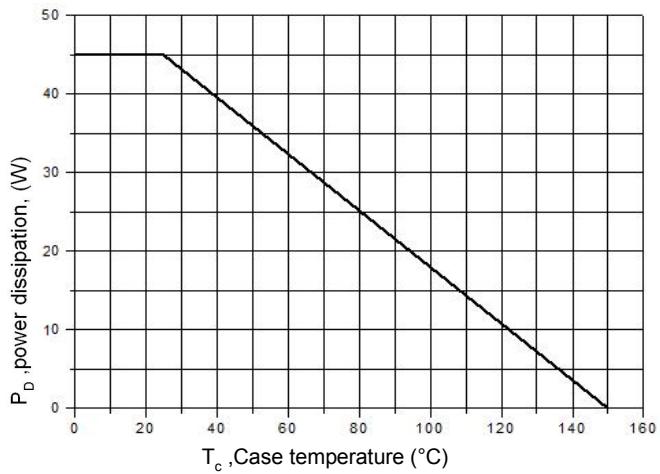


Figure 8. Gate Charge Characteristics

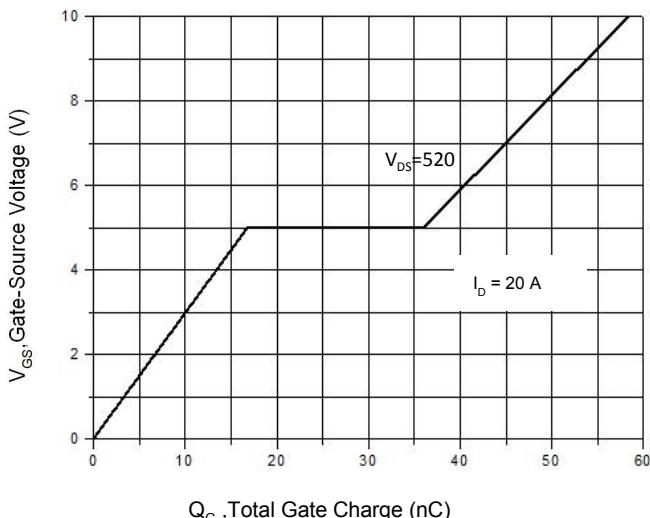


Figure 10. Maximum Safe Operating Area

TO-247/TO-220

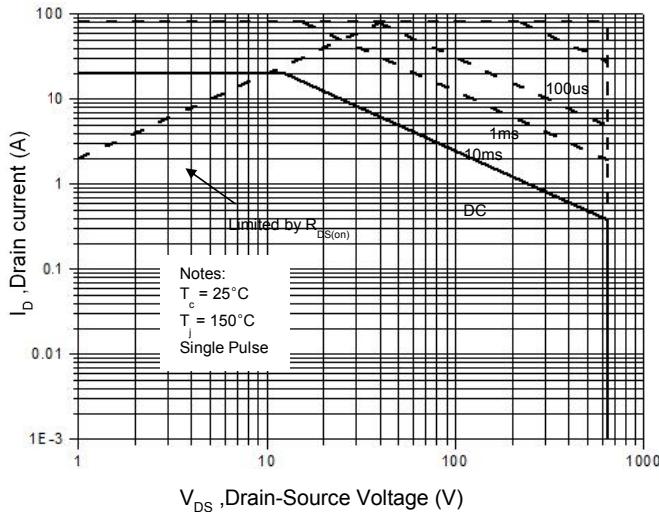


Figure 12. Power Dissipation vs. Temperature

TO-247/TO-220

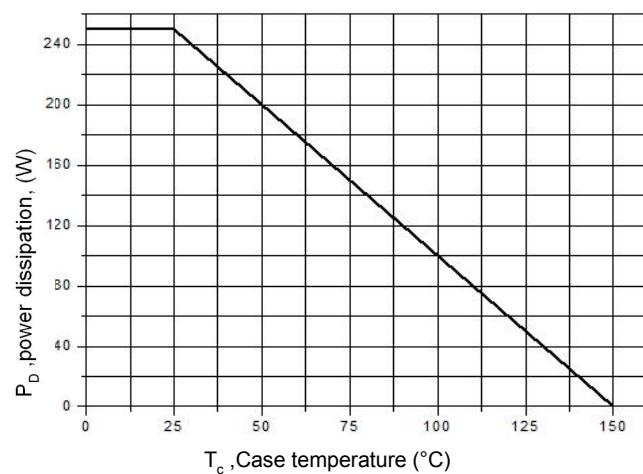


Figure 13. Continuous Drain Current vs. Temperature

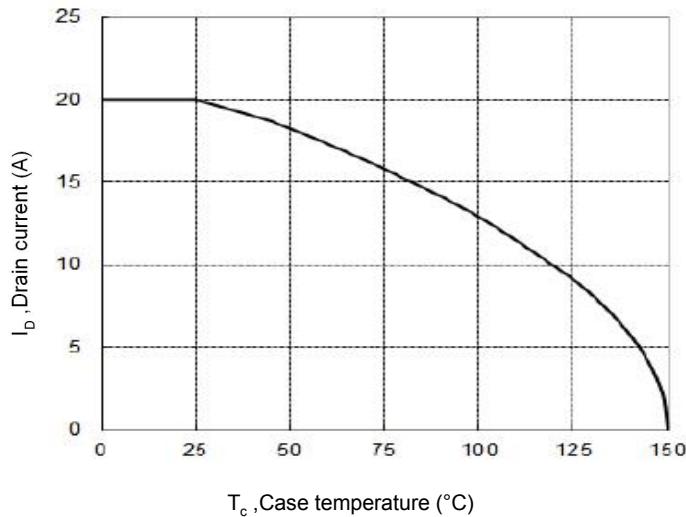


Figure 14. Body Diode Transfer Characteristics

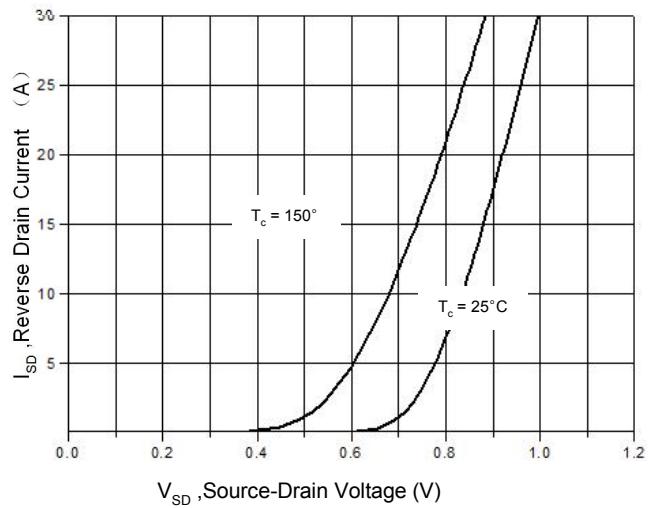


Figure 15 Transient Thermal Impedance , Junction to Case, TO-220F

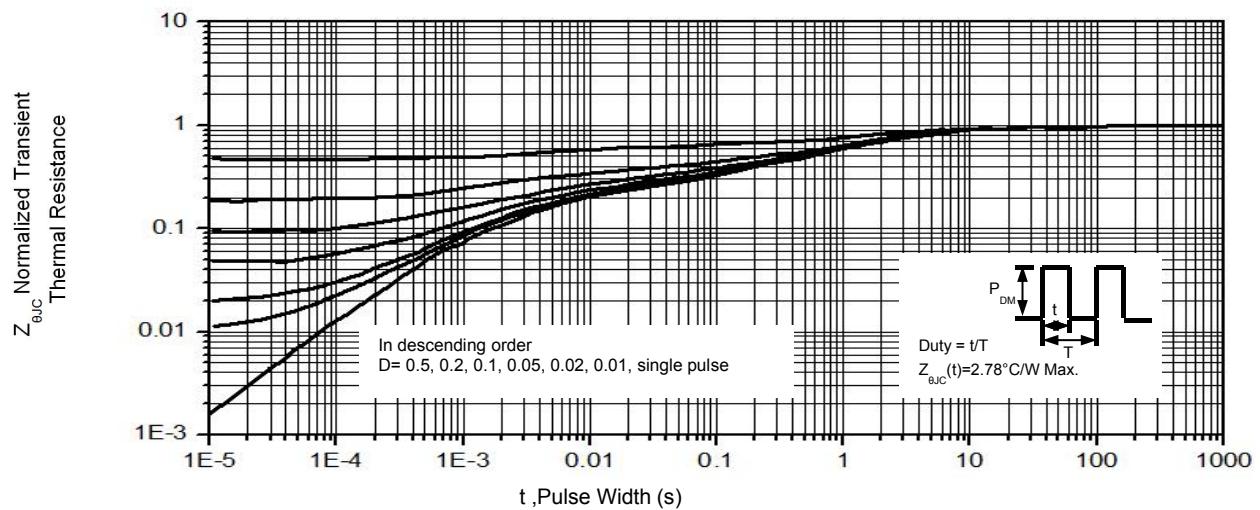
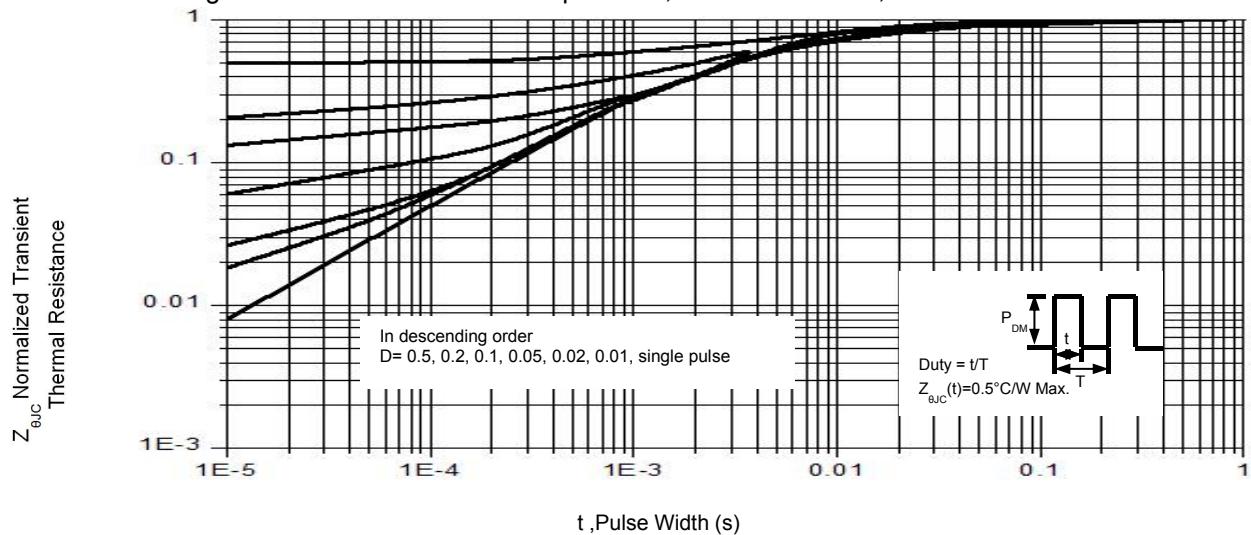
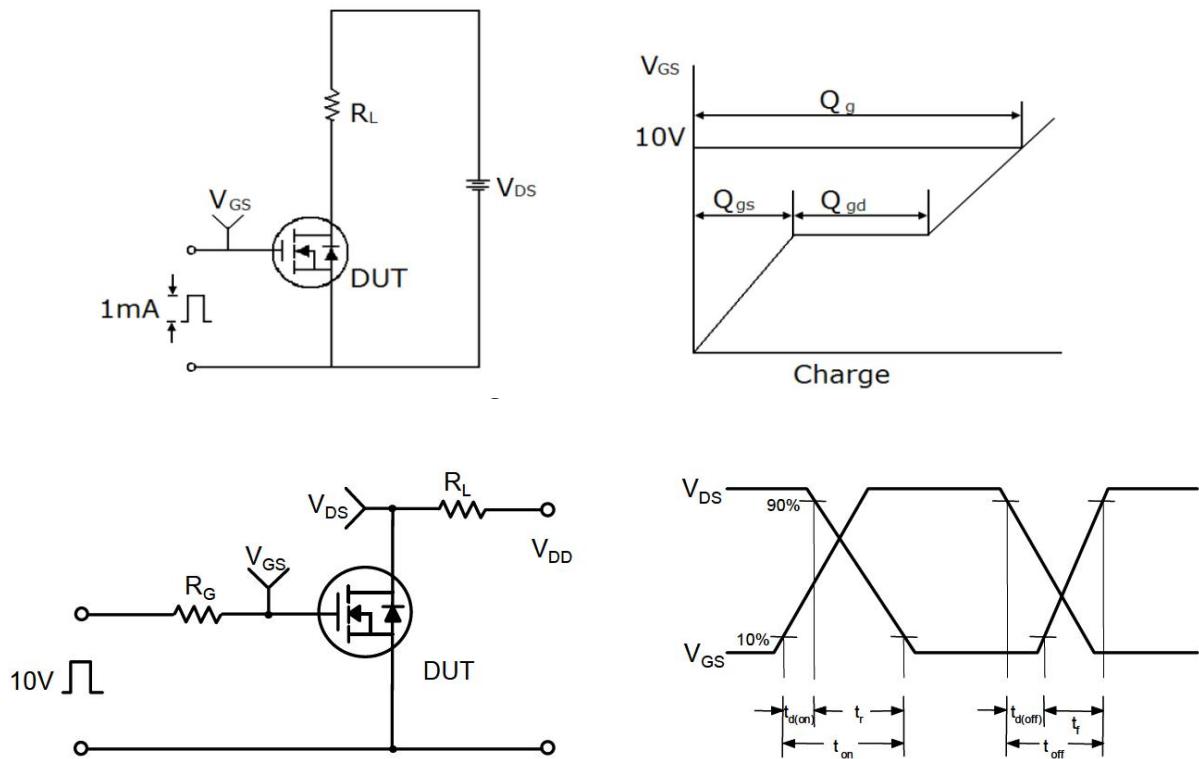


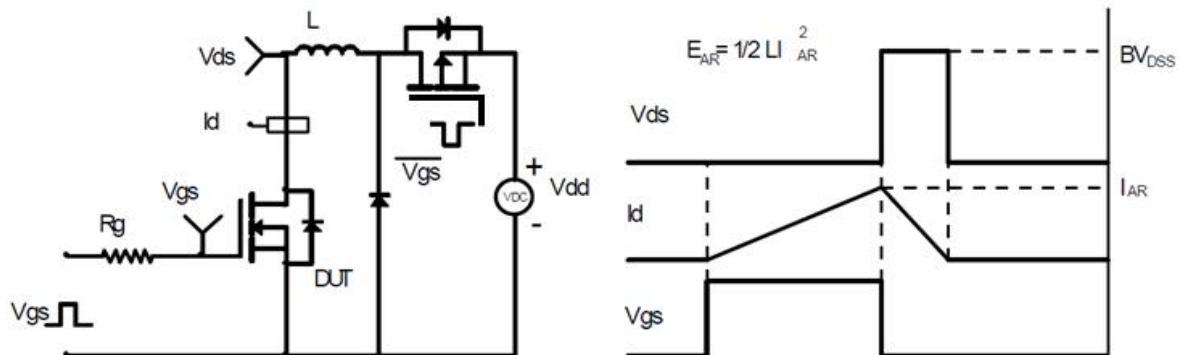
Figure 16. Transient Thermal Impedance, Junction to Case, TO-247/TO-220



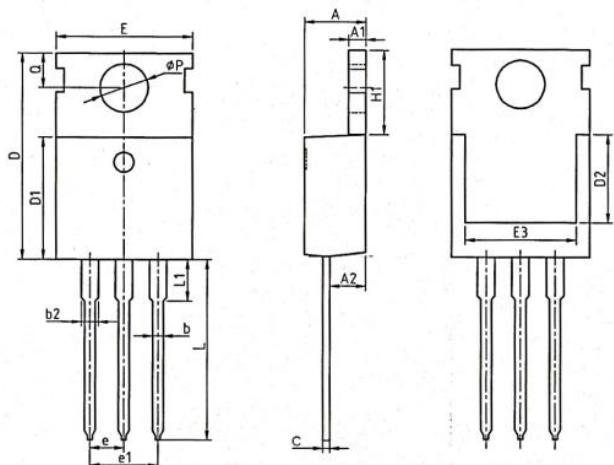
Gate Charge Test Circuit & Waveform



Unclamped Inductive Switching Test Circuit & Waveforms

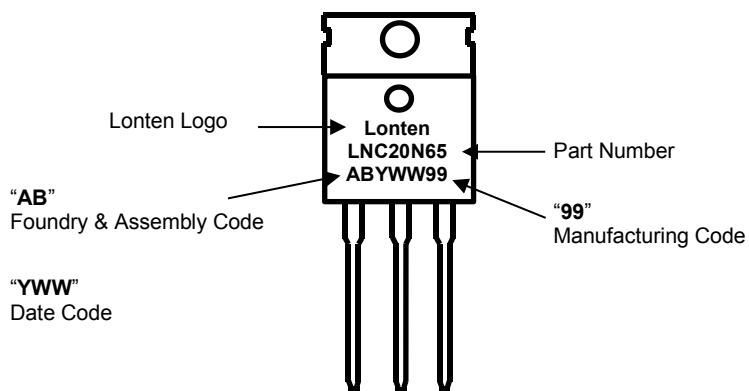


Mechanical Dimensions for TO-220

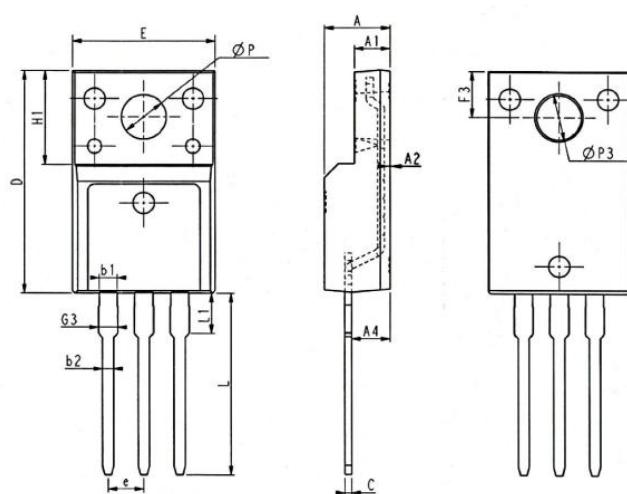


| SYMBOL | COMMON DIMENSIONS | | | | | |
|--------|-------------------|-------|-------|--------|-------|-------|
| | MM | | | INCH | | |
| | MIN | NOM | MAX | MIN | NOM | MAX |
| A | 4.37 | 4.57 | 4.70 | 0.172 | 0.180 | 0.185 |
| A1 | 1.25 | 1.30 | 1.40 | 0.049 | 0.051 | 0.055 |
| A2 | 2.20 | 2.40 | 2.60 | 0.087 | 0.094 | 0.102 |
| b | 0.70 | 0.80 | 0.95 | 0.028 | 0.031 | 0.037 |
| b2 | 1.17 | 1.27 | 1.47 | 0.046 | 0.050 | 0.058 |
| c | 0.45 | 0.50 | 0.60 | 0.018 | 0.020 | 0.024 |
| D | 15.10 | 15.60 | 16.10 | 0.594 | 0.614 | 0.634 |
| D1 | 8.80 | 9.10 | 9.40 | 0.346 | 0.358 | 0.370 |
| D2 | 5.50 | — | — | 0.217 | — | — |
| E | 9.70 | 10.00 | 10.30 | 0.382 | 0.394 | 0.406 |
| E3 | 7.00 | — | — | 0.276 | — | — |
| e | 2.54BSC | | | 0.1BSC | | |
| e1 | 5.08BSC | | | 0.2BSC | | |
| H1 | 6.25 | 6.50 | 6.85 | 0.246 | 0.256 | 0.270 |
| L | 12.75 | 13.50 | 13.80 | 0.502 | 0.531 | 0.543 |
| L1 | — | 3.10 | 3.40 | — | 0.122 | 0.134 |
| Øp | 3.40 | 3.60 | 3.80 | 0.134 | 0.142 | 0.150 |
| Q | 2.60 | 2.80 | 3.00 | 0.102 | 0.110 | 0.118 |

TO-220 Part Marking Information

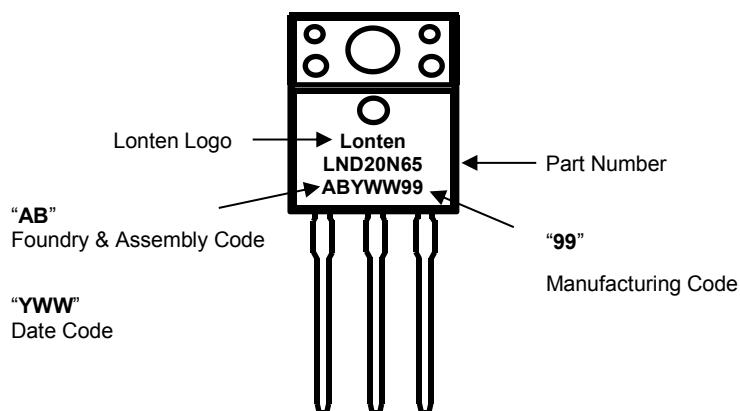


Mechanical Dimensions for TO-220F

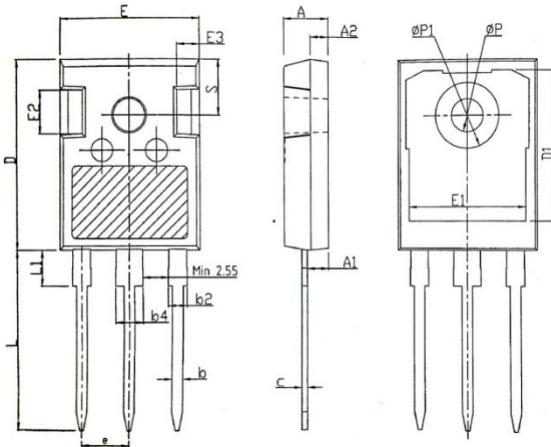


| SYMBOL | COMMON DIMENSIONS | | | INCH | | |
|--------|-------------------|-------|-------|----------|-------|-------|
| | MIN | NOM | MAX | MIN | NOM | MAX |
| E | 9.96 | 10.16 | 10.36 | 0.392 | 0.400 | 0.408 |
| A | 4.50 | 4.70 | 4.90 | 0.177 | 0.185 | 0.193 |
| A1 | 2.34 | 2.54 | 2.74 | 0.092 | 0.100 | 0.108 |
| A2 | 0.30 | 0.45 | 0.60 | 0.012 | 0.002 | 0.024 |
| A4 | 2.65 | 2.76 | 2.96 | 0.104 | 0.109 | 0.117 |
| C | 0.40 | 0.50 | 0.65 | 0.016 | 0.020 | 0.026 |
| D | 15.57 | 15.87 | 16.17 | 0.613 | 0.625 | 0.637 |
| H1 | 6.70REF | | | 0.264REF | | |
| e | 2.54BSC | | | 0.1BSC | | |
| ØP | 3.03 | 3.18 | 3.38 | 0.119 | 0.125 | 0.133 |
| L | 12.68 | 12.98 | 13.28 | 0.499 | 0.511 | 0.523 |
| L1 | 2.88 | 3.03 | 3.18 | 0.113 | 0.119 | 0.125 |
| ØP3 | 3.15REF | | | 0.124REF | | |
| F3 | 3.15 | 3.30 | 3.45 | 0.124 | 0.130 | 0.136 |
| G3 | 1.25 | 1.35 | 1.55 | 0.049 | 0.053 | 0.061 |
| b1 | 1.18 | 1.28 | 1.43 | 0.046 | 0.050 | 0.056 |
| b2 | 0.70 | 0.80 | 0.95 | 0.028 | 0.031 | 0.037 |

TO-220F Part Marking Information

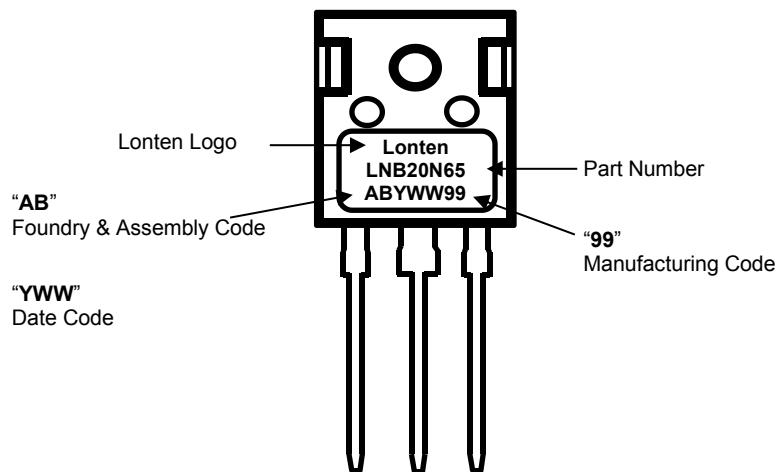


Mechanical Dimensions for TO-247



| SYMBOL | mm | | |
|--------|---------|-------|-------|
| | MIN | NOM | MAX |
| A | 4.80 | 5.00 | 5.20 |
| A1 | 2.21 | 2.41 | 2.59 |
| A2 | 1.85 | 2.00 | 2.15 |
| b | 1.11 | 1.21 | 1.36 |
| b2 | 1.91 | 2.01 | 2.21 |
| b4 | 2.91 | 3.01 | 3.21 |
| c | 0.51 | 0.61 | 0.75 |
| D | 20.80 | 21.00 | 21.30 |
| D1 | 16.25 | 16.55 | 16.85 |
| E | 15.50 | 15.80 | 16.10 |
| E1 | 13.00 | 13.30 | 13.60 |
| E2 | 4.80 | 5.00 | 5.20 |
| E3 | 2.30 | 2.50 | 2.70 |
| e | 5.44BSC | | |
| L | 19.82 | 19.92 | 20.22 |
| L1 | — | — | 4.30 |
| ØP | 3.40 | 3.60 | 3.80 |
| ØP1 | — | — | 7.30 |
| S | 6.15BSC | | |

TO-247 Part Marking Information



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